# imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



## Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



## LIXYS

### DSB80C45HB

### preliminary

$V_{RRM}$	=	45V
l <sub>fav</sub>	= 2x	40 A
V <sub>F</sub>	=	0.59V

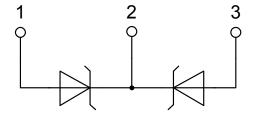
High Performance Schottky Diode Low Loss and Soft Recovery Common Cathode

Schottky Diode Gen<sup>2</sup>

Part number DSB80C45HB



Backside: cathode



#### Features / Advantages:

- Very low Vf
- Extremely low switching losses
- Low Irm values
- Improved thermal behaviour
- High reliability circuit operation
  Low voltage peaks for reduced
- protection circuits
- Low noise switching

### Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

#### Package: TO-247

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

IXYS reserves the right to change limits, conditions and dimensions.

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### DSB80C45HB

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Schottky					Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit	
	max. non-repetitive reverse blocki	ng voltage	$T_{VJ} = 25^{\circ}C$			45	V	
	max. repetitive reverse blocking vo	oltage	$T_{VJ} = 25^{\circ}C$			45	V	
I <sub>R</sub>	reverse current, drain current	$V_R = 45 V$	$T_{VJ} = 25^{\circ}C$			15	mA	
		$V_R = 45 V$	$T_{vJ} = 100^{\circ}C$			150	mA	
V <sub>F</sub>	forward voltage drop	I <sub>F</sub> = 40 A	$T_{vJ} = 25^{\circ}C$			0.62	V	
		I <sub>F</sub> = 80 A				0.90	V	
		I <sub>F</sub> = 40 A	T <sub>vJ</sub> = 125°C			0.59	V	
		I <sub>F</sub> = 80 A				0.88	V	
I FAV	average forward current	T <sub>c</sub> = 125°C	T <sub>vJ</sub> = 150°C			40	A	
		rectangular d = 0.5						
V <sub>F0</sub>	threshold voltage		T <sub>vJ</sub> = 150°C			0.31	V	
r <sub>F</sub>	slope resistance } for power lo	ss calculation only				7	mΩ	
R <sub>thJC</sub>	thermal resistance junction to case	2				0.7	K/W	
R <sub>thCH</sub>	thermal resistance case to heatsin	k			0.25		K/W	
P <sub>tot</sub>	total power dissipation		$T_c = 25^{\circ}C$			180	W	
	max. forward surge current	t = 10 ms; (50 Hz), sine; $V_R = 0 V$	$T_{VJ} = 45^{\circ}C$			600	A	
CJ	junction capacitance	$V_R$ = 5 V f = 1 MHz	$T_{VJ} = 25^{\circ}C$		1.38		nF	
E <sub>AS</sub>	non-repetitive avalanche energy	$I_{AS}$ = tbd A L = tbd µH	$T_{VJ} = 25^{\circ}C$				mJ	
I <sub>AR</sub>	repetitive avalanche current	$V_{A} = 1.5 \cdot V_{R}$ typ.: f = 10 kHz					A	

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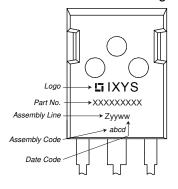


### DSB80C45HB

### preliminary

Package TO-247			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
I <sub>RMS</sub>	RMS current	per terminal 1)			50	A
T <sub>vj</sub>	virtual junction temperature		-55		150	°C
T <sub>op</sub>	operation temperature		-55		125	°C
T <sub>stg</sub>	storage temperature		-55		150	°C
Weight				6		g
M <sub>D</sub>	mounting torque		0.8		1.2	Nm
F <sub>c</sub>	mounting force with clip		20		120	Ν

#### **Product Marking**



#### Part number

- D = Diode S = Schottky Diode
- B = ultra low VF
- 80 = Current Rating [A]
- C = Common Cathode
- 45 = Reverse Voltage [V] HB = TO-247AD (3)

[	Ordering	Part Number	Marking on Product	Delivery Mode	Quantity	Code No.	
	Standard	DSB80C45HB	DSB80C45HB	Tube	30	504883	

Equivalent Circuits for Simulation			* on die level	T <sub>vJ</sub> = 150 °C
	)- <u>R</u> o-	Schottky		
V <sub>0 max</sub>	threshold voltage	0.31		V
$R_{0 max}$	slope resistance *	4.5		mΩ

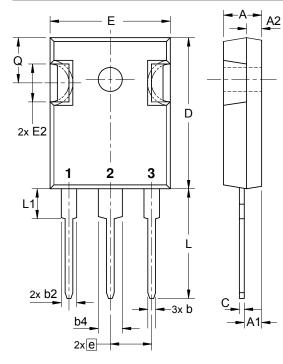
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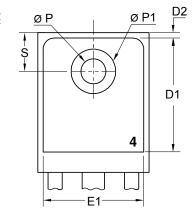
## LIXYS

### DSB80C45HB

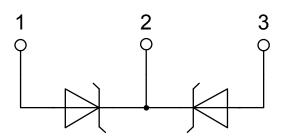
preliminary

### Outlines TO-247





Sym.	Inches		Millim	eter	
	min.	max.	min.	max.	
А	0.185	0.209	4.70	5.30	
A1	0.087	0.102	2.21	2.59	
A2	0.059	0.098	1.50	2.49	
D	0.819	0.845	20.79	21.45	
E	0.610	0.640	15.48	16.24	
E2	0.170	0.216	4.31	5.48	
е	0.215	BSC	C 5.46 BSC		
L	0.780	0.800	19.80	20.30	
L1	-	0.177	-	4.49	
ØР	0.140	0.144	3.55	3.65	
Q	0.212	0.244	5.38	6.19	
S	0.242	BSC	6.14	BSC	
b	0.039	0.055	0.99	1.40	
b2	0.065	0.094	1.65	2.39	
b4	0.102	0.135	2.59	3.43	
с	0.015	0.035	0.38	0.89	
D1	0.515	-	13.07	-	
D2	0.020	0.053	0.51	1.35	
E1	0.530	-	13.45	-	
ØP1	-	0.29	-	7.39	



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